## NSN 5962-01-370-0994

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Maximum Power Dissipation Rating:
880.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
An/fps-124
Features Provided:
Schottky and bipolar
Inclosure Material:
Ceramic
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Bipolar metal-oxide semiconductor
Case Outline Source And Designator:
D-8 mil-m-38510
Current Rating Per Characteristic:
-30.00 milliamperes collector cutoff current, dc, base open absolute and 5.00 milliamperes average forward current averaged over a full
60-hz cycle absolute
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital, schottky, bipolar 4096 prom
Voltage Rating And Type Per Characteristic:
-0.5 volts total supply and 7.0 volts total supply
Time Rating Per Chacteristic:
45.00 nanoseconds access
Memory Device Type:
Prom
Hybrid Technology Type:
Monolithic
Test Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). And 96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

#### **Terminal Type And Quantity:**

20 printed circuit

#### **Specification Data:**

67268-5962-8769002ra government standard and 56232-1219251-215 manufacturers source control

### **Departure From Cited Designator:**

Altered by programming, marking & testing

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Demilitarization:

Yes - demil/mli

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